NSN 5961-01-034-2230

Diode Semiconductor Device - Page 1 of 1



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nclosure Material:
Metal
Overall Length:
0.500 inches
Mounting Facility Quantity:
1
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
Between 0.667 inches and 0.700 inches
Thread Size:
0.250 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
42.0 nonrepetitive peak reverse voltage, peak total value and 60.0 reverse voltage, instantaneous
Current Rating Per Characteristic:
600.00 amperes source cutoff current preset
Test Data Document:
32577-925201 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.,
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Thread Series Designator:
Jnf
Terminal Type And Quantity:
1 threaded stud and 1 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Filg:
A110a0